VS-VSKJS409/150

Vishay Semiconductors





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AAP Gen 7 (TO-240AA)

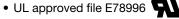
PRIMARY CHARACTERISTICS			
I _{F(AV)} 400 A			
V _R	150 V		
Package	AAP Gen 7 (TO-240AA)		
Circuit configuration	Two diodes common anode		

MECHANICAL DESCRIPTION

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 175 °C T_J operation
- · Low forward voltage drop
- High frequency operation
- Low thermal resistance



- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

BENEFITS

- · Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- · Easy mounting on heatsink

ELECTRICAL DESCRIPTION / APPLICATIONS

The VS-VSKJS409/150 Schottky rectifier common anode has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters,

freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rectangular waveform	400	А	
V _{RRM}		150	V	
I _{FSM}	t _p = 5 μs sine	20 000	А	
V _F	200 A _{pk} , T _J = 125 °C	0.85	V	
TJ	Range	-55 to +175	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL VS-VSKJS409/150		UNITS	
Maximum DC reverse voltage	V _R	150	V	
Maximum working peak reverse voltage	V _{RWM}	150	v	

RoHS COMPLIANT

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	OL TEST CONDITIONS VAL		VALUES	UNITS
Maximum average	per module		50 % duty cycle at T _C = 105 °C, rectangular waveform		400	
forward current	per leg	I _{F(AV)}			200	
Maximum peak one cycle			5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	20 000	A
non-repetitive surge curre	nt	IFSM	1 310	rated V _{RRM} applied	2300	
Non-repetitive avalanche	energy	E_{AS} T _J = 25 °C, I _{AS} = 1.8 A, L = 10 mH		15	mJ	
Repetitive avalanche curre	ent	I _{AR}	$\frac{1}{3} \qquad \begin{array}{l} \text{Current decaying linearly to zero in 1 } \mu s \\ \text{Frequency limited by } T_J \text{ maximum } V_A = 1.5 \text{ x } V_B \text{ typical} \end{array} \qquad 1$		1	А

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	L TEST CONDITIONS VA		VALUES	UNITS
	V _{FM}	200 A	T _J = 25 °C	1.03	v
		400 A		1.33	
Maximum forward voltage drop		200 A	- T _J = 125 °C	0.85	
		400 A		1.13	
Maximum reverse leakage current	I _{RM}	T _J = 25 °C	V _R = Rated V _R	6	mA
Maximum reverse leakage current		T _J = 125 °C		85	ША
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		6000	pF
Typical series inductance	Ls	Measured lead to lead 5 mm from package body		5.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs
Maximum RMS insulation voltage	V _{INS}	50 Hz		3000 (1 min) 3600 (1 s)	V

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range)	T _J , T _{Stg}		-55 to 175	°C
Maximum thermal resistance, junction to case per leg		R _{thJC}	R _{thJC} DC operation		°C/W
Typical thermal resistance, case to heatsink per module		R _{thCS}		0.1	
Approximate weight				75	g
				2.7	oz.
Mounting torque ± 10 % -	to heatsink		A mounting compound is recommended and the torque	4	- Nm
	busbar		should be rechecked after a period of 3 h to allow for the spread of the compound.	3	
Case style			JEDEC®	TO-240AA co	ompatible

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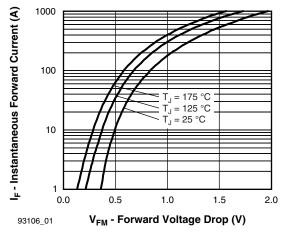
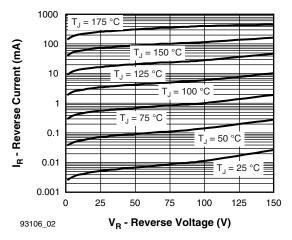
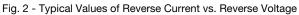


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)





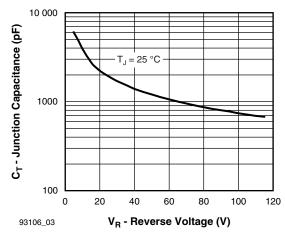
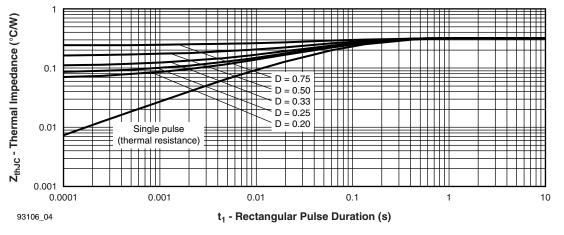
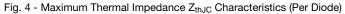


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



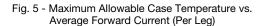


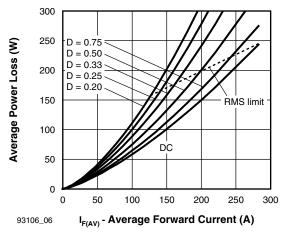
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180 Allowable Case Temperature (°C) 160 140 120 DC 100 80 60 Square wave (D = 0.50)40 80 % rated $\rm V_R$ applied 20 See note (1) 0 0 100 200 300 400 500 I_{F(AV)} - Average Forward Current (A) 93106 05





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Fig. 6 - Forward Power Loss Characteristics (Per Leg)

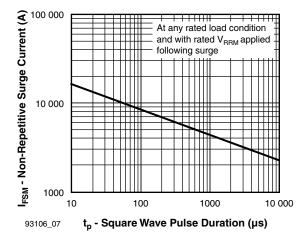


Fig. 7 - Maximum Non-Repetitive Surge Current

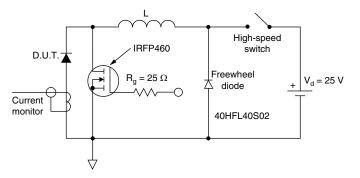


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \ - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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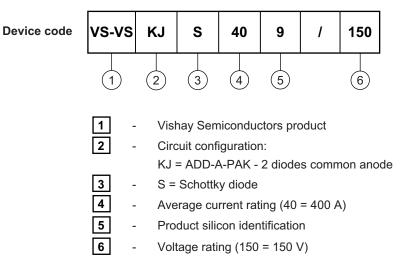
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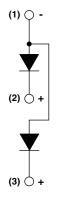
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ORDERING INFORMATION TABLE



CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95369			

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ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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